NSN 5961-01-302-8574

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-302-8574 **Inclosure Material:** Glass **Overall Length:** 0.225 inches **Terminal Length:** 1.000 inches **Overall Diameter:** 0.110 inches **Mounting Method: Terminal Features Provided:** Hermetically sealed case and quality assurance level txv **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 200.0 reverse gate to source breakdown voltage **Current Rating Per Characteristic:** 25.00 amperes source cutoff current absolute **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius ambient air **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** Yes - demil/mli

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